2A, 1.5MHz, Synchronous Step-Down Converter

FEATURES

- 2A output current
- Current mode operation
- High efficiency up to 95%
- Shutdown current < 1μA
- 2.5V to 5.5V supply voltage
- Over temperature protection
- Constant frequency operation
- Full duty ratio, 0 100% in dropout
- RoHS Compliant and Lead (Pb) Free

APPLICATIONS

- Cellular phones
- PDAs and smart phones
- MP3 players
- Digital still cameras
- Slim-type DVD
- Wireless and DSL card
- Microprocessors and DSP core supplies
- Portable instruments

ORDERING INFORMATION

PART	PACKAGE	Output	Ship, Quantity
ZTP7108T	TSOT23-5L	Adjust.	Tape and Reel
ZTP7108D	TDFN 2x2-6L	Adjust.	Tape and Reel

DESCRIPTION

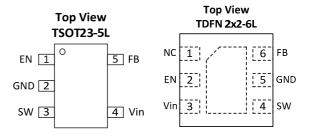
ZTP7108 is a high efficiency step down DC/DC converter operated with current mode and constant frequency. The internal switch and synchronous rectifier are integrated for high efficiency. External Schottky diodes are not required. The supply current is only 120 μ A during operation and drops to less than 1 μ A in shutdown. ZTP7108 can supply 2A of load current from 2.5V to 5.5V supply voltage.

The switching frequency is set at 1.5MHz, allowing the use of small surface mount inductors and capacitors. It can run 100% duty cycle for low dropout application.

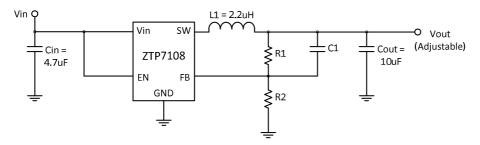
The output voltage of ZTP7108 is adjustable from the FB pin.

ZTP7108 is RoHS compliant and Lead (Pb) Free.

Pins Configuration



Typical Application Circuit, Adjustable Output Voltage



Vout = $V_{FB} \times (1 + R1/R2)$

with R1 = 300k for typical application,

and C1 should be in the range between 10pF and 47pF for component selection.

Absolute Maximum Ratings

(Note 1)

Vin to GND0.3V to +6V
SW Voltage to GND –0.3V to Vin+0.3V
EN Voltage to GND –0.3V to Vin
FB/Vout to GND0.3V to Vin
SW Peak Current 3A
Operating Temperature Range40°C to +85°C
Junction Temperature+150°C
Storage Temperature Range65°C to +150°C
Lead Temperature (Soldering 10s) +260°C
ESD Classification Class 2

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

Electro-Static Discharge Sensitivity

This integrated circuit can be damaged by ESD. It is recommended that all integrated circuits be handled with proper precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure.

Block Diagram



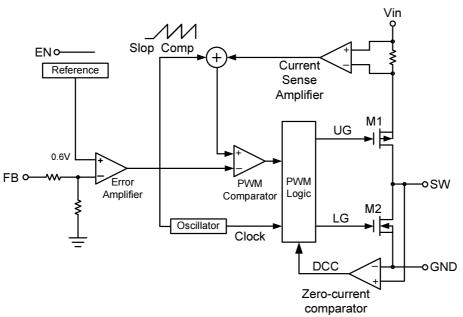
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TSOT23-5L:	
Thermal Resistance, θ_{JA}	250°C/W
Thermal Resistance, θ_{JC}	130°C/W
TDFN 2x2-6L:	
Thermal Resistance, θ_{JA}	. 120°C/W
Thermal Resistance, θ_{JC}	20°C/W

Recommended Operating Conditions (Note 3)

Supply Input Voltage	+2.5V to +5.5V
Junction Temperature Range	–40°C to +125°C
Ambient Temperature Range	. –40°C to +85°C

Pins Description

TSOT 23-5L	TDFN 2x2-6L	Symbol	Description	
1	2	EN	Enable control input pin.	
2	5	GND	Ground pin.	
3	4	SW	Power switch output.	
4	3	Vin	Main supply pin.	
	1	NC	No connected.	
5	6	FB	Feedback pin. Vout=0.6×(1+R1/R2). Add optional C1 to speed up transient response.	



Electrical Specifications

PARAMETER	Symbol	TEST CONDITIONS	MIN	ТҮР	МАХ	UNIT
Supply Voltage	Vin		2.5		5.5	V
Output Voltage Line Regulation	∆Vout	Vin = 2.5V to 5.5V	-3		3	%V
Output Voltage Load Regulation	V _{LR}		-3		3	%
Reference Voltage	V _{REF}	For adjustable Vout	0.588	0.6	0.612	V
Output Range (Adjustable Voltage)	Vout	Vin = 2.5V to 5.5V	-3		+3	%
Shutdown Current	۱ _s	V _{EN} = 0V		0.1	1	μΑ
Quiescent Current	Ι _Q	V_{EN} = Vin, V_{FB} = $V_{REF} \times 1.1$ No Switching		100		μΑ
SW Leakage Current	I _{LEAK}	V _{EN} = 0V, V _{SW} = 0V or Vin	-1		1	μA
PMOSFET On Resistance*	R _{DSONP}	I _{SW} = 100mA		110		mΩ
NMOSFET On Resistance*	R _{DSONN}	I _{sw} = -100mA		95		mΩ
PMOSFET Current Limit*	I _{LIM}	Duty cycle = 100% Current Pulse Width < 1ms		3		А
Oscillator Frequency	Fosc		1.2	1.5	1.8	MHz
Thermal Shutdown Threshold*	Ts			160		°C
EN High Level Input Voltage	V _{ENH}	-40°C ≤ T _A ≤ 85°C	1.5			V
EN Low Level Input Voltage	V _{ENL}	-40°C ≤ T _A ≤ 85°C			0.4	V
EN Input Current	I _{EN}	V _{EN} = 0V to Vin	-1		1	μA

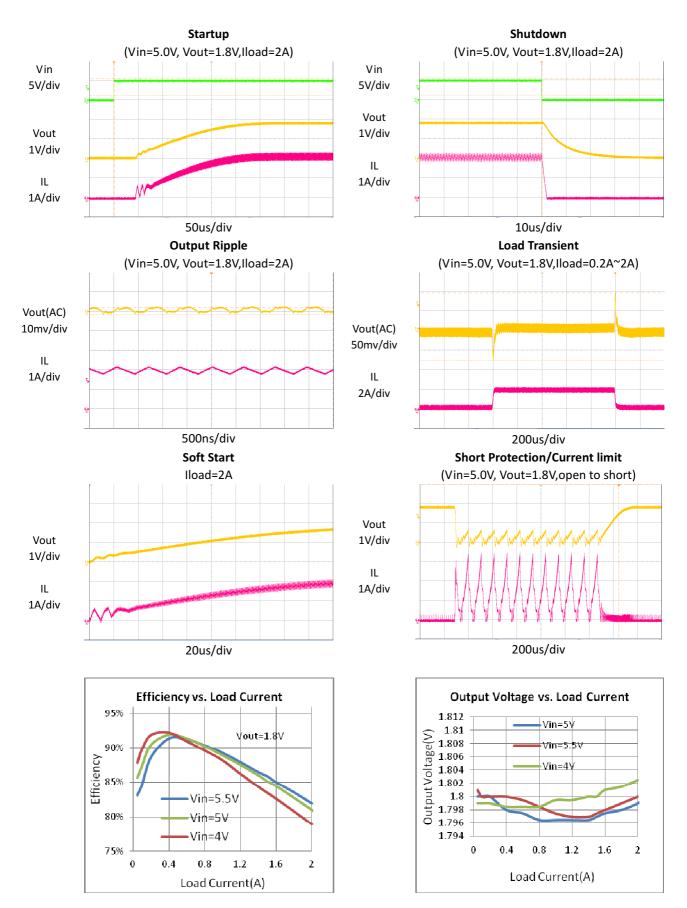
* Guaranteed by design not for test.

Note 1: Stresses beyond those listed "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions may affect device reliability.

Note 2: θ_{JA} is measured in the natural convection at TA = 25°C on a low effective single layer thermal conductivity test board of JEDEC 51-3 thermal measurement standard. Pin 2 of TSOT23-5 packages is the case position for θ_{JC} measurement. Measured at the exposed pad of the package.

Note 3: The device is not guaranteed to function outside its operating conditions.

Typical Characteristics



FUNCTIONAL DESCRIPTION

Overview

The ZTP7108 is a constant frequency current mode PWM step down converter. ZTP7108 is optimized for low voltage, Li-ion battery, powered applications where high efficiency and small size are critical. The device integrates both a main switch and a synchronous rectifier, which provides high efficiency and eliminates an external Schottky diode. ZTP7108 can achieve 100% duty cycle. The duty cycle D of a step down converter is defined as:

$$\mathsf{D} = \mathsf{T}_{\mathsf{ON}} \times \mathsf{F}_{\mathsf{OSC}} \times 100\% \approx \frac{\mathsf{Vout}}{\mathsf{Vin}} \times 100\%$$

Where T_{ON} is the main switch on time, F_{OSC} is the oscillator frequency (1.5MHz), Vout is the output voltage and Vin is the input voltage.

Current Mode PWM Control

Slope compensated current mode PWM control provides stable switching and cycle-by-cycle current limit for superior load and line response and protection of the internal main switch and synchronous rectifier. ZTP7108 switches at a constant frequency (1.5MHz) and regulates the output voltage. During each cycle the PWM comparator modulates the power transferred to the load by changing the inductor peak current based on the feedback error voltage. During normal operation, the main switch is turned on for a certain time to ramp the inductor current at each rising edge of the internal oscillator, and switched off when the peak inductor current is above the error voltage. When the main switch is off, the synchronous rectifier will be turned on immediately and stay on until either the next cycle starts or the inductor current drops to zero. The device skips pulses to improve efficiency at light load.

Dropout Operation

ZTP7108 allows the main switch to remain on for more than one switching cycle and increases the duty cycle while the input voltage is dropping close to the output voltage. When the duty cycle reaches 100%, the main switch is held on continuously to deliver current to the output up to the P MOSFET current limit. The output voltage then is the input voltage minus the voltage drop across the main switch and the inductor.

Short Circuit Protection

The ZTP7108 has short circuit protection. When the output is shorted to ground, the oscillator frequency is reduced to prevent the inductor current from increasing beyond the P MOSFET current limit. The frequency will return to the normal values once the short circuit condition is removed and the Vout reaches regulated voltage.

Maximum Load Current

The ZTP7108 can operate down to 2.5V input voltage; however the maximum load current decreases at lower input due to large IR drop on the main switch and synchronous rectifier. The slope compensation signal reduces the peak inductor current as a function of the duty cycle to prevent sub-harmonic oscillations at duty cycles greater than 50%. Conversely the current limit increases as the duty cycle decreases.

APPLICATION INFORMATION

Inductor Selection

A 2.2 μ H to 4.7 μ H is recommended for general used. The value of inductor depends on the operating frequency. Higher frequency allows smaller inductor and capacitor but increases internal switching loss. Two inductor parameters should be considered, current rating and DCR. The inductor with the lowest DCR is chosen for the highest efficiency.

The inductor value can be calculated as:

 $L \ge [V_{OUT}/(f \times \Delta I_L)](1 - V_{OUT}/V_{IN})$

 ΔI_L : inductor ripple current, which is defined as:

 $\Delta I_{L} = V_{OUT}[(1 - V_{OUT}/V_{IN})/(L \times f)]$ (General Setting) $\approx \alpha \times I_{O-MAX}$ ($\alpha = 0.2 \sim 0.4$)

The inductor should be rated for the maximum output current (I_{O-MAX}) plus the inductor ripple current (ΔI_L) to avoid saturation. The maximum inductor current (I_{L-MAX}) is given by:

 $I_{L-MAX} = I_{O-MAX} + \Delta I_L/2$

Capacitor Selection

The small size of ceramic capacitors are ideal for ZTP7108 applications. X5R and X7R types are recommended because they retain their capacitance over wider voltage and temperature ranges than other types, such as Y5V or Z5U. A 4.7 μ F input capacitor and a 10 μ F output capacitor are sufficient for most ZTP7108 applications.

When selecting an output capacitor, consider the output ripple voltage and the ripple current. The ESR of capacitor is a major factor to the output ripple. For the best performance, a low ESR output capacitor is required. The ripple voltage is given by:

 $\Delta V_{O} = \Delta I_{L} [ESR + 1/(8 \times f \times C_{O})]$

Output Voltage Programming (Adjustable Voltage Version)

The output voltage of ZTP7108 is set by the resistor divider according to the following formula:

 $V_{OUT} = V_{FB} \times (1 + R1/R2)$

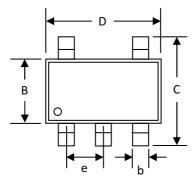
R1 is the upper resistor of the voltage divider. For transient response reasons, a small feed-forward capacitor (C_F) is required in parallel to the upper feedback resistor, and 33pF is recommended.

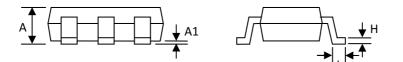
Checking Transient Response

The regulator loop response can be checked by looking at the load transient response. Switching regulators take several cycles to respond to a step in load current. When a load step occurs, V_{OUT} will be shifted immediately by an amount equal to ($\Delta I_{LOAD} \times ESR$), where ESR is the effective series resistance of C_{OUT} . ΔI_{LOAD} will also begin to charge or discharge C_{OUT} , which generates a feedback error signal. Then the regulator loop will act to return V_{OUT} to its steady state value. During this recovery time, V_{OUT} can be monitored for overshoot or ringing that will indicate the stability problem.

The discharged bypass capacitors are effectively put in parallel with C_{OUT} , causing a rapidly drop in V_{OUT} . No regulator can deliver enough current to prevent this problem if the load switch resistance is low and it is driven quickly. The only solution is to limit the rise time of the switch drive, so that the load rise time will be limited to approximately (25 × C_{LOAD}).

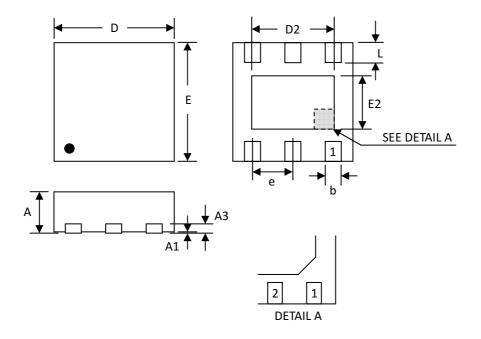
PACKAGE DIMENSION (TSOT23-5L)





Symbol	Dimensio	ns in mm	Dimensions in Inch		
	Min	Max	Min	Max	
А	0.700	1.100	0.028	0.043	
A1	0.000	0.130	0.000	0.005	
В	1.500	1.700	0.059	0.067	
b	0.300	0.559	0.012	0.022	
С	2.500	3.100	0.098	0.122	
D	2.800	3.100	0.110	0.122	
е	0.950) BSC	0.037 BSC		
Н	0.080	0.200	0.003	0.008	
L	0.200	0.800	0.008	0.031	

PACKAGE DIMENSION (TDFN 2x2-6L)



SYMBOLS	DIMENSION (MM)			DIMENSION (INCH)			
51110015	MIN	NOM	MAX	MIN	NOM	MAX	
А	0.700		0.800	0.028		0.031	
A1	0.000		0.050	0.000		0.002	
A3	0.175		0.250	0.007		0.010	
b	0.200		0.350	0.008		0.014	
D	1.950	2.000	2.050	0.077	0.079	0.081	
D2	1.000		1.450	0.039		0.057	
E	1.950	2.000	2.050	0.077	0.079	0.081	
E2	0.500		0.850	0.020		0.033	
е	0.650			0.026			
L	0.250		0.400	0.010		0.016	